Sintering and dielectric properties of a technical porcelain prepared from economical natural raw materials

(Sinterização e propriedades dielétricas de uma porcelana técnica preparada a partir de matérias-primas naturais de baixos custos)

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Abstract

In this study, the production of a technical porcelain, for the ceramic dielectric applications by using economical natural raw materials, was investigated. The basic porcelain composition was selected consisting of 30 wt% kaolin, 45 wt% potash-feldspar and 25 wt% quartz. The obtained phases in the sintered samples were investigated by X-ray diffraction, Fourier transform infrared spectroscopy analysis, and scanning electron microscopy images. It has been confirmed by these techniques that the main crystalline phases were quartz and mullite. Dielectric measurements of technical porcelains have been carried out at 1 kHz from room temperature to 200 °C. The dielectric constant, loss factor, dielectric loss tangent, and resistivity of the porcelain sample sintered at 1160 °C were 22-25, 0.32-1.80, 0.006-0.07, and 0.2-9 x 1013 Ω.cm, respectively. The value of dielectric constant was significantly high when compared to that of conventional porcelains which did not exceed generally 9.

Keywords: porcelain, kaolin, feldspar, quartz, sintering, dielectric properties.

Resumo

Neste estudo, foi investigada a produção de uma porcelana técnica para aplicações cerâmicas dielétricas pelo uso de matérias-primas naturais de baixos custos. A composição básica da porcelana foi selecionada consistindo de 30% de caulim, 45% de feldspato potássico e 25% de quartzo. As fases obtidas nas amostras sinterizadas foram investigadas por difração de raios X, espectroscopia no infravermelho com transformada de Fourier e imagens de microscopia eletrônica de varredura. Foi confirmado por estas técnicas que as principais fases cristalinas foram quartzo e mulita. Medidas dielétricas das porcelanas técnicas foram realizadas a 1 kHz entre a temperatura ambiente de 200 °C. A constante dielétrica, fator de perda, tangente de perda dielétrica e resistividade da amostra de porcelana sinterizada a 1160 °C foram 22-25, 0,32-1,80, 0,006-0,07 e 0,2-9 x 1013 Ω.cm, respectivamente. O valor de constante dielétrica foi significativamente alto quando comparado ao de porcelanas convencionais que geralmente não excede 9.

Palavras-chave: porcelana, caulim, feldspato, quartzo, sinterização, propriedades dielétricas.

INTRODUCTION

The use of traditional ceramics, using raw materials instead of industrial chemicals is becoming of more and more interest mainly due to the lower price of the raw material available. Algeria is one of the countries in the world that have abundantly available raw materials, such as calcium carbonates (CaCO₃), dolomite (CaCO₃‧MgCO₃), bones (natural derived hydroxyapatite [Ca₁₀(PO₄)₆‧(OH)₂]), kaolin, feldspar and quartz. Many works have already been published for valorizing these native raw materials for the production of advanced ceramics [1-3], bioceramics [4-6], and ceramic membranes [7-15]. In this way, an attempt has been done in order to use two types of kaolin (halloysites type and Tamazart), feldspar and quartz local raw materials for porcelain production. Porcelain insulators and porcelain shells are important devices in the operation of plants and transformer substations insulation and wire supporting [16]. The electrical porcelains are usually prepared by using pressure. However, in many cases, the use of glass forming components to ceramic samples result in decrease in firing temperature, amount of crystalline phases due to their dissolution in the glass phase during sintering, and mechanical and thermal properties of the porcelain. The manufacture of porcelain having ameliorated properties at low sintering temperatures is possible up to certain limits. Indeed, the properties of the porcelain are mainly determined by the presence of sufficient quantity of well-crystallized mullite. The sintering temperature of porcelain is therefore connected
to the development of the processes of mullite formation in
the clay-nonplastics-flux system, i.e. the firing temperature of
the porcelain must not be lower than the temperature at which
the mullite forming processes can be completed (not below
1150 to 1200 °C) [17].

The utilization of ceramic materials such as electrical
insulators goes back to 1850 when Werner von Siemens
introduced in the construction of electrical air lines the use of
electro-technical porcelains. During this long period of time,
it has been realized that several characteristic properties of
porcelain (e.g., mechanical strength, high-power dielectric
strength, and corrosion resistance) as a ceramic product cannot
be obtained in other materials. Electrical porcelains can be
classified as follows based on its purpose and properties [18,
19]: i) normal high-voltage porcelains used in the production
of high-voltage line and apparatus insulators; ii) high-voltage
porcelains with an increased quartz content used to make high-
voltage apparatus insulators with improved electromechanical
properties; iii) high-voltage alumina porcelains for high-voltage
apparatus insulators with elevated mechanical strengths; iv)
low-voltage porcelains used in the production of insulators
and insulating parts for plants up to 500 V generating direct
and alternating current and weak current plants [20]. Today,
the growing demand for porcelain in the field of electrical
engineering, caused by the importance of electric energy in
modern society, motivates many research projects in order to
obtain the best properties for the requirements and applications
of porcelain insulators [21].

The potential uses of electrical ceramics in many
applications are determined by its dielectric properties. For
example, dielectrics with dielectric constant above 12 are
generally materials for capacitors and transducers. The ceramic
capacitors are one of the most widely used discrete electronic
components that play a very important role in electronic
industries. In the recent years, a rapid development in the
ceramic capacitor technology has been achieved to meet the
needs of advancement in microelectronics and communication.
It is envisaged that more applications of ceramic capacitors
will be found in future [7]. In the present investigation, the
dielectric properties of the technical porcelain were studied.
Consequently, this part is devoted only to the sintering and
the dielectric properties of technical porcelains. In the present
investigation, preparation of technical porcelains using
Algerian raw materials and dielectric properties was carried
out. Dielectric constant (ε’), loss factor (ε’’) and dielectric loss
tangent (tanθ) were studied. Finally, qualitative estimation
of quartz and mullite has been done to study the dielectric
properties of the selected composition using X-ray diffraction
studies, Fourier transform infrared spectroscopy analyses, and
scanning electron microscopy (SEM) images.

**EXPERIMENTAL PROCEDURE**

The main raw materials used for the preparation of the
porcelain were Djebel Debegh kaolin, halloysite type
(KDD2), Tamazert kaolin (KT2), Ain Barber potassium
feldspar, and Ben Azouz quartz sand. All these raw materials
presented in this study were derived from deposits in Algeria.
Chemical composition is an important factor because of its
effects on ceramic properties. The chemical compositions
of the three used raw materials were determined by X-ray
fluorescence spectroscopy. This study investigated a unique
porcelain type percentage composition of 30 wt% kaolin (20
wt% KDD2 and 10 wt% KT2), 45 wt% feldspar and 25 wt% quarts.

The raw materials pulverized into powders ready for
batching were used: raw materials were wet milled and
homogenized in a modified milling system for 6 h to obtain
the typical size distribution used in industrial productions.
The main characteristics of this original milling system are
detailed elsewhere [22]. It is mainly composed of 4 parts:
a metallic cylinder, a teflon bottle, a motor, and a rotational
system. The latter makes the cylinder to rotate with a constant
speed. In order to avoid the adhesion of the powder on its
sides, the bottle has been placed obliquely in the middle of the
cylinder within an angle α. This device has also four springs
fixed at 4 corners of its support so as to allow the bottle to
vibrate gently or strongly. This system works smoothly and
silently, contrarily to the usual noisy vibratory milling system
due to its motor. These last two characteristics are the origin
of the obtained multidirectional rotation. As a result, powerful
and continuous collisions may occur between the hard
milling balls and the powder particles which substantially
reduce the powder particle size. Many interesting published
works have used this original milling system [23-25]; they
concern hydroxyapatite based ceramics [26-28], wollastonite
[29-31], diopside [32-34], anorthite [35, 36], and others [37-
42]. By drying, the test specimens for firing tests, shaped as
discs of about 13 mm diameter and about 2 mm thickness,
were obtained after uniaxial pressing of powders at 75
MPa. Subsequently, the compacts were sintered at different
temperatures (1080 to 1260 °C) for 2 h. A constant heating
rate of 5 °C/min was maintained in each firing. The samples
were left inside the oven to naturally cool down until room
temperature. For the dielectric properties characterization,
only samples sintered at 1160 °C were selected.

Different techniques were used to investigate the
properties of samples. The morphology, microstructure of
the raw materials and samples were observed using a
SEM (Hitachi, JSM-6301 F, Japan) working at 7 kV as
accelerating voltage. Before SEM observation, all samples
were gold coated. Phase compositions of prepared samples
were identified by using X-ray diffraction (XRD, Bruker,
D8 Advance, Germany) with a CuKα radiation (λ= 0.154
nm) and a Ni filter, working voltage of 40 kV, and working
current of 30 mA. Fourier transform infrared spectroscopy
(FTIR, Perkin Elmer, Spectrum BX LX 185255) was also
used for samples characterization. The density of green and
dried specimens was geometrically determined from their
weight and dimensional measurements, which were accurate
to ± 0.001 g and ± 0.01 mm, respectively. In order to create
c an adhesion path for electrical measurements on the samples,
electrodes with silver paste on the top and bottom faces were
used. The electrodes were fired at 300 °C for 20 min with
a heating rate of 5 °C/min. Subsequently, all measurements were undertaken at a temperature range from 20 to 190 °C on a LCR meter connected to a furnace with a heating rate of 5 °C/min (Fig. 1). The dielectric constant was calculated as the measured capacitance multiplied by the sample geometrical factor. The dielectric constant (\( \varepsilon' \)) and loss factor (\( \varepsilon'' \)) were determined from the following equations:

\[
\varepsilon' = C/C_0 = C.I/(\varepsilon_0.A)
\]  

(A)

\[
\varepsilon'' = \varepsilon'.\tan\delta
\]  

(B)

where \( C_0 \) is the capacitance of a two-electrode system with air as the dielectric, \( C \) is the capacitance with the sample as a dielectric, \( I \) is the thickness of the sample, \( A \) is the effective area between the electrodes, and \( \varepsilon_0 \) is the free space permittivity. The dielectric loss tangent (\( \tan\delta \)) was given directly by the instrument. The resistivity (\( \rho \)) values were calculated as the ratio:

\[
\rho = 1/\sigma = 1/(\omega.\tan\delta.\varepsilon'.\varepsilon_0)
\]  

(C)

where \( \sigma \) is the conductivity, and \( \omega \) is the frequency.

The variation of bulk density of samples versus sintering temperature is illustrated in Fig. 5. The obtained curve may be divided into two main stages. The first stage (from 1080 to 1160 °C) was characterized by a sharp increase in the impurities characterized by non-plastic properties. All the raw materials used for porcelain samples production were chemically analyzed (Table I). These results indicate that kaolin, quartz and feldspar were of the common type generally used in porcelain products with moderately small amounts of impurities. In feldspar, iron oxide content is considerably lower than in conventional feldspathic fluxes (\( \text{Fe}_2\text{O}_3 < 1 \text{ wt}\% \)). The presence of potassium oxide proportion in feldspar confirms the existence of orthoclase. The quartz contains small amounts of \( \text{CaO} \) and \( \text{Fe}_2\text{O}_3 \), about 1.87 wt\% and 0.74 wt\%, respectively (Table I), contrarily to other works which were characterized by remarkable amounts of 6.78 wt\% \( \text{CaO} \) and 4.57 wt\% \( \text{Fe}_2\text{O}_3 \) [7]. Additionally, the SEM micrographs of the two types kaolin (KDD2 and KT2) powders used in this work are given in Fig. 2: KDD2 crystallizes nicely in the form of naturally nano-rode halloysite crystals (Fig. 2a); by contrast, KT2 powder crystals had platelet form (Fig. 2b). However, \( \text{Fe}_2\text{O}_3 \) is not the only factor responsible for the coloration of ceramic wares. Other constituents such as \( \text{CaO} \), \( \text{MgO} \), \( \text{MnO} \) and \( \text{TiO}_2 \) can appreciably modify the color of fired clays. The quantities of the components depend on the mineralogical nature of the clays, on the clay particle size distribution and finally on their reactivity to the melting minerals. These oxides (\( \text{CaO} \), \( \text{MgO} \), \( \text{MnO} \) and \( \text{TiO}_2 \)) may play a significant role towards densification, phase transformation and mullite grain growth in the porcelain product. Consequently, the presence of such oxides and different raw materials such as the two kaolin types in a porcelain product and kaolin-alumina-silica mixture may enhance their properties.

XRD pattern of sample sintered at 1160 °C is shown in Fig. 3a. The crystalline phases (quartz and mullite) dispersed in the vitreous phase are identified by XRD in samples fired above 1160 °C. In all patterns, quartz and mullite phases were found to be the major crystalline phases. Typical bands, assigned to quartz and mullite, are distinguished in the FTIR spectrum in Fig. 3b. The absorption peaks at 459, 778 and 798 cm\(^{-1}\) correspond to the vibration of non-bridging oxygen (Si-O-). The peaks at 778 and 798 cm\(^{-1}\) correspond also to the vibration of non-bridging oxygen (Si-O-) associated with K\(^+\), and the peaks 700, 1081 and 1169 cm\(^{-1}\) correspond to the vibration of bridging oxygen (Si-O-Si) while the peak at 544 cm\(^{-1}\) corresponds to the vibration of (Si-O-Al) for the sample sintered at 1160 °C for 2 h [43-46]; this peak may belong to the mullite phase. The sharp spitted band corresponding to (Si-O-Si) is a diagnosis to identify quartz. The peaks at 1630 and 3454 cm\(^{-1}\) which are typically used to determine water content and these vibrations correspond to H-O-H [47]. Fig. 4 illustrates the morphologies of sample sintered at 1160 °C for 2 h. This microstructure consists of angular quartz particles and secondary mullite crystals with needle shape that are clearly identified by SEM. Indeed, it confirms the results obtained by both XRD and FTIR techniques.

The variation of bulk density of samples versus sintering temperature is illustrated in Fig. 5. The obtained curve may be divided into two main stages. The first stage (from 1080 to 1160 °C) was characterized by a sharp increase in the

**RESULTS AND DISCUSSION**

The mineralogical composition of the clays influences plasticity. The type of mineral clay and the particle size distribution as well as the quantity and the type of accessory materials alter plasticity. Iron minerals (mainly \( \text{Fe}_2\text{O}_3 \)) and calcium minerals (mainly \( \text{CaCO}_3 \)) are among the main components. The presence of potassium oxide proportion in feldspar and the nature of the clays, on the clay particle size distribution and finally on their reactivity to the melting minerals. These oxides (\( \text{CaO} \), \( \text{MgO} \), \( \text{MnO} \) and \( \text{TiO}_2 \)) may play a significant role towards densification, phase transformation and mullite grain growth in the porcelain product. Consequently, the presence of such oxides and different raw materials such as the two kaolin types in a porcelain product and kaolin-alumina-silica mixture may enhance their properties.

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The variation of bulk density of samples versus sintering temperature is illustrated in Fig. 5. The obtained curve may be divided into two main stages. The first stage (from 1080 to 1160 °C) was characterized by a sharp increase in the
bulk density of samples. The bulk density reached its higher value (about 2.41 g/cm$^3$) for sample sintered at 1160 °C for 2 h. Then, at the second stage (1160 to 1260 °C) a significant decrease in bulk density was reached. This decrease in bulk density may be due to the increase in sintering temperature. Densification takes place above 1160 °C, since the thermal reaction between decomposed kaolin and feldspar starts. Solid-state sintering is a process of consolidation of particles under the sintering temperatures below the melting point (1080 to 1160 °C). Sintering during firing forms solid bonds between particles. Such bonding reduces the surface energy by reducing the free surface. In this process, the grain boundaries are partially eliminated through grain growth and the pore volume is reduced, leading to a condensed mass. The temperature necessary to induce such bonding depends upon the characteristics of both starting materials and the particle size distribution. Many theories describing various stages and transport phenomena have been proposed to describe the sintering phenomenon. Solid-state sintering takes place between particles of single or multiple phases.
where homogenization takes place during the sintering of mixed phases that form a single-phase product. However, in many cases, sintering takes place in the presence of a liquid phase, especially when many phases are present, and is known as liquid-phase sintering. The sintering behavior of the fired samples was evaluated by using the verification curves, which present the variation in properties of a ceramics as a function of firing temperature for otherwise identical firing schedules in terms of heating rate, cooling rate and holding time at peak temperatures. Densification curves help establishing the optimum firing temperature and the firing range at which the open porosity reaches a minimum, which usually corresponds to higher mechanical strength values [45]. The latter phenomenon may also be related to the formation of glassy phase which probably affects the proper interlocking of mullite needles in the microstructure [48]. At higher temperature, the lower bulk density value was due to a change in composition of the glassy phase. Elastic bond relaxation at a high sintering temperature may also be considered as a contributing factor [49]. In porcelain densification, this mechanism might be partly related to the crystallization of secondary mullite from the glassy melt but its crystal growth must be from the glassy melt. Nevertheless, its crystal growth must be limited to the optimum size. This mechanism could not be accepted as the predominant one in the densification of porcelain due to the creation of a large amount of liquid phase at maximum firing temperature which surrounds the grains completely.

Figure 5: Bulk density of samples sintered for 2 h. as a function of temperature measured at 1 kHz is shown in Fig. 6b. The dielectric constant increases with the increase of temperature in temperature range from ambient to about 70 °C. Thereafter, it remains fairly constant up to around 160 °C and then increases again, achieving the maximum value of about 25. Based on a mixture rule using various theories to predict the dielectric constants of materials, the dielectric constant of the composites was found to be situated in 12-24 range [50]. In ceramic materials, ions can be used as carriers to provide electrical conduction. The degree of conductivity is largely dependent on the energy that must be given to ions to move from one lattice position to the next. At low temperatures, conductivity is low. However, if the temperature is high enough to overcome the energy barrier for lattice diffusion, the conductivity increases. Another reason which can be given is some form of interactions between the dielectric and Ag electrodes which may be considered as responsible for this relatively higher dielectric constant value. Moreover, the lattice defects formed could accelerate the mass transport process. The existence of lattice defects such as vacancies and interstitials in the structure helps conduction [51], and promotes grain growth furthermore. Generally, the grain size may influence the dielectric constant [52]. Dielectrics with dielectric constant above 12 are generally materials for capacitors and transducers. The porcelain sample is suitable for this application in the present form, because of its relatively high dielectric constant. The relatively high dielectric constant has to be encouraged. That was the case when the sintering of this kind of porcelain product was carried out using a microwave heating in a modified domestic multi-mode cavity [7].

Figure 6 shows the dielectric constant (\( \varepsilon' \)) of the sintered porcelain product as a function of temperature measured at 1 kHz is shown in Fig. 6b. The increase in \( \varepsilon'' \) with temperature can be explained by the relaxation phenomenon which is divided into three parts: conduction loss, dipole loss and vibration loss [53]. At low temperatures, conduction losses have a minimum value. As the temperature increases conductivity increases and so do the conduction losses. As a result, the value of \( \varepsilon'' \) increases with the increase in temperature. The dielectric loss tangent (tanδ) of the sintered porcelain product versus temperature is illustrated in Fig. 6c. The variation of tanδ as a function of temperature at 1 kHz, for sample sintered at 1160 °C, is consistent with the \( \varepsilon'' \) behavior (Fig. 6b). In the dielectric materials, boundaries, defects, space charge
formation, lattice distortions, etc. could produce current absorption resulting in a decrease of dielectric loss tangent (tanδ) [53]. However, the porcelain product is composed of phases such as mullite (Al₆Si₂O₁₃) and undissolved quartz (SiO₂) crystals embedded in a continuous glassy phase, originating from feldspar [7], and may be from other low melting impurities in the raw materials. Porcelain electrical properties are generally dependent on the properties of each of these phases and impurities, at room and elevated temperatures. Chaudhuri and Parker [54] have evaluated whether the presence of mullite can influence or not the dielectric properties of porcelain using mineralizers in porcelain formulations to increase their concentrations.

The variation of resistivity of samples sintered at 1160 °C is shown in Fig. 7. It gradually decreases with the increase in test temperature and the maximum value of the resistivity is about 9 x 10¹³ Ω.cm. This high value of resistivity may be attributed to the high activation energy of calcium ions which make them less mobile as reported by [55]; among the less mobile modifier ions, e.g., alkaline earth with comparatively large ions and high charge (divalent), CaO is one of the most effective addition for dielectric bodies. This relatively high value confirms that the technical porcelain is an insulator material because the electrical resistivity values of porcelain are also in the range of 10¹² to 10¹⁴ Ω.cm [56].

The porcelain insulators are processed from three types of raw materials: plastic materials, clay or kaolin [Al₂Si₂O₅(OH)₄], give plasticity to the ceramic mixture; flint or quartz (SiO₂)/alumina (Al₂O₃) maintain the shape of the formed product during firing; and feldspar [KNaₓ(AlSi₃O₁₀)] used as fluxing [57-60]. In the present study, the glassy phase is derived from the potash feldspar and quartz component in the porcelain composition. Glass phase has a dominant influence on electrical and dielectric properties of fired ceramics. These properties are determined by the concentration and mobility of K⁺ and/or Na⁺ ions in this phase [61]. In the presence of large amount of glassy phase in the structure [7], the mobile ions such as K⁺ finds an easy path to move and hence increases the conductivity [54]. It is believed that the dielectric constant of porcelain increases with the presence of K⁺ and Na⁺.
cations and decreases when they are replaced by Ca\textsuperscript{2+}, Mg\textsuperscript{2+} and Ba\textsuperscript{2+} cations [62]. On the other hand, mullite, which is a crystalline phase, has a vital role on electrical properties [63, 64].

CONCLUSIONS

The present work is an attempt for the fabrication of technical porcelains using low-price natural local raw materials. The proposed composition was 30 wt\% kaolin (20 wt\% KDD2 and 10 wt\% KT2), 45 wt\% K-feldspar and 25 wt\% quartz. According to the obtained results, the main formed crystalline phases were quartz and mullite. The optimum sintering conditions were 1160 °C for 2 h. Actually, the porcelain product presents dielectric constant (\(\varepsilon\)), loss factor (\(\varepsilon''\)), dielectric loss tangent (tan \(\delta\)) and resistivity values of 22, 0.8, 0.035 and 9 \(\times\) 10\(^5\) \(\Omega\).cm, respectively, at room temperature. This material has potential to be used for dielectrics in commercial capacitor applications. Thus, the insulator could be used as a capacitor bushing where low charge storage capacity is desirable. The porcelain sample may be suitable for this application in the present form because of its high dielectric constant.

REFERENCES


(Rec. 20/10/2015, Rev. 20/03/2016, Ac. 23/05/2016)